

## SANYO Semiconductors

DATA SHEET

Discontinued

Preliminary

# STK412-150C-E — Two-Channel Power Switching System Audio Power IC, 150W+150W

#### Overview

The STK412-150C-E is a class H audio power amplifier hybrid IC that features a built-in power supply switching circuit. This IC provides high efficiency audio power amplification by controlling (switching) the supply voltage supplied to the power devices according to the detected level of the input audio signal.

#### Applications

• Audio power amplifiers.

#### Features

- High output power by using power MOSFETs.
- Output load impedance:  $R_L = 8\Omega$  to  $6\Omega$  supported
- Using insulated metal substrate that features superlative heat dissipation characteristics that are among the highest in the industry.

#### **Series Models**

	STK412-150C-E	STK412-170C-E	
Output (0.7%/20Hz to 20kHz)	150W×2 channels ( $R_L=6\Omega$ )	180W×2 channels (R <sub>L</sub> =4 $\Omega$ )	
Max. rated V <sub>H</sub> (quiescent)	±95V	±95V	
Max. rated V <sub>L</sub> (quiescent)	±61V	±60V	
Recommended operating V <sub>H</sub>	±57V	±54V	
Recommended operating $V_L$	±38V	±37V	
Dimensions (excluding pin height)	78.0mm×44.0mm×9.0mm		

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

SANYO Semiconductor Co., Ltd. www.semiconductor-sanyo.com/network

## STK412-150C-E

#### **Specifications**

Absolute maximum ratings at Ta = 25°C (excluding rated temperature items), Tc=25°C unless otherwise specified

Parameter	Symbol	Conditions	Ratings	Unit
V <sub>H</sub> maximum quiescent supply voltage 1	V <sub>H</sub> max (1)	When no signal	±95	V
V <sub>H</sub> maximum supply voltage 2	V <sub>H</sub> max (2)	R <sub>L</sub> ≥6Ω, 150W, 50ms	±85	V
VL maximum quiescent supply voltage 1	V <sub>L</sub> max (1)	When no signal	±61	V
V <sub>L</sub> maximum supply voltage 2	V <sub>L</sub> max (2)	R <sub>L</sub> ≥6Ω, 150W, 50ms	±55	V
Maximum voltage between V <sub>H</sub> and V <sub>L</sub> *4	V <sub>H</sub> -V <sub>L</sub> max	No load	60	V
Thermal resistance	өј-с	Per power transistor	1.3	°C/W
Junction temperature	Tj max	Both the Tj max and Tc max conditions must be met.	150	°C
IC substrate operating temperature	Tc max		125	°C
Storage temperature	Tstg		-30 to +125	°C
Allowable load shorted time *3	ts	$V_{H}{=}{\pm}57V,V_{L}{=}{\pm}38V,R_{L}{=}6\Omega,f{=}50Hz,$ $P_{O}{=}150W,1{-}channel active$	0.3	s

#### Electrical Characteristics at Tc=25°C, RL=6 $\Omega$ , Rg=600 $\Omega$ , VG=30dB, VZ=18V, non-inductive load RL

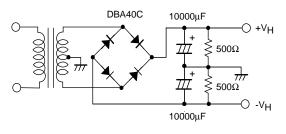
		Conditions *1						Ratings			
Parameter	Symbol		′CC (V)	f (Hz)	P <sub>O</sub> (W)	THD (%)		min	typ	max	unit
Output power	P <sub>O</sub> (1)	V <sub>H</sub> VL	±57 ±38	20 to 20k		0.7		150			W
Total harmonic distortion	THD (1)	V <sub>H</sub> VL	±57 ±38	20 to 20k	150				0.4		%
Frequency characteristics	fL, fH	∨ <sub>H</sub> ∨L	±57 ±38		1.0		+0 -3dB		20 to 50	K	Hz
Input impedance	ri	∨ <sub>H</sub> ∨L	±57 ±38	1k	1.0				55		kΩ
Output noise voltage *2	V <sub>NO</sub>	∨ <sub>H</sub> ∨L	±68 ±46				Rg=2.2kΩ			1.0	mVrms
Quiescent current	ICCO	VH	±68				D.			70	mA
		VL	±46				RL=∞			100	ША
Output neutral voltage	V <sub>N</sub>	V <sub>H</sub> VL	±68 ±46					-70	0	+70	mV

#### [Remarks]

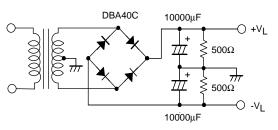
\*1: Unless otherwise specified, use a constant-voltage power supply to supply power when inspections are carried out.

- \*2: The output noise voltage values shown are peak values read with a VTVM. However, an AC stabilized (50Hz) power supply should be used to minimize the influence of AC primary side flicker noise on the reading.
- \*3: Use the designated transformer power supply circuit shown in the figure below for the measurements of allowable load shorted time and output noise voltage.
- \*4: Design circuits so that  $(|V_H|-|V_L|)$  is always less than 40V when switching the power supply with the load connected.
- \*5: Set up the VL power supply with an offset voltage at power supply switching (VL-VO) of about 8V as an initial target.
- \*6: Weight of independent IC: 38.6g

Package dimensions (length×width×height): 429mm×245mm×275mm



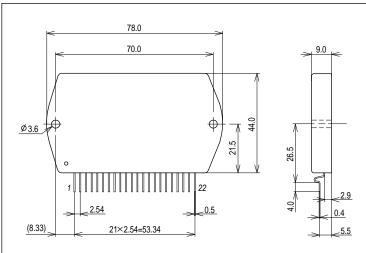
Designated transformer power supply (MG-250 equivalent)



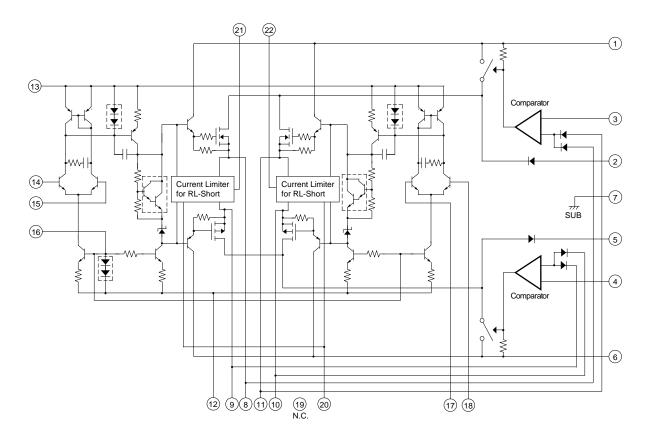
Designated transformer power supply (MG-200 equivalent)

# Package Dimensions

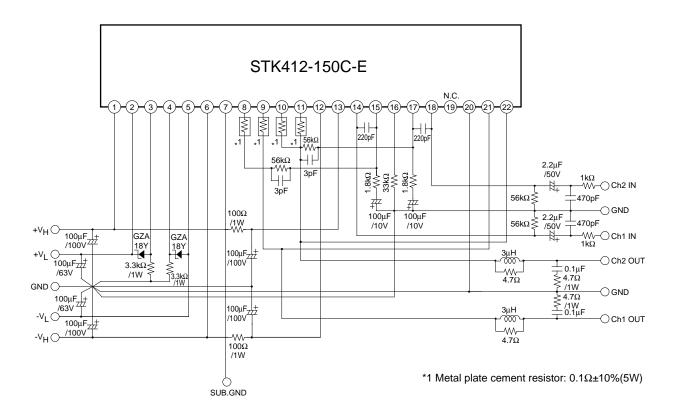
unit:mm (typ)



## **Internal Equivalent Circuit**



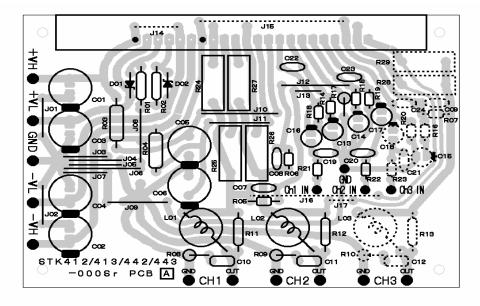
## **Application Circuit Example**



# Pin Assignments

PIN No.	PIN Symbol	PIN Assignment
1	+V <sub>H</sub>	+V <sub>H</sub> Power Supply Voltage
2	+VL	+VL Power Supply Voltage
3	+Vref	+Side Shift Voltage Reference
4	-Vref	-Side Shift Voltage Reference
5	-VL	-V <sub>L</sub> Power Supply Voltage
6	-V <sub>H</sub>	-V <sub>H</sub> Power Supply Voltage
7	SUB GND	H-IC Sub GND
8	Ch1 +RE	Ch1 +Side Emitter Output
9	Ch1 -RE	Ch1 -Side Emitter Output
10	Ch2 -RE	Ch2 -Side Emitter Output
11	Ch1 +RE	Ch1 +Side Emitter Output
12	-Pre V <sub>H</sub>	-Side Pre. Supply Voltage
13	+Pre V <sub>H</sub>	+Side Pre. Supply Voltage
14	Ch1 IN	Ch1 Input
15	Ch1 NF	Ch1 Negative Feedback
16	Bias	Bias
17	Ch2 NF	Ch2 Negative Feedback
18	Ch2 IN	Ch1 Input
19	N.C.	No. Component
20	GND	GND
21	Ch2 FB	Ch2 Feedback for Protection
22	Ch1 FB	Ch1 Feedback for Protection

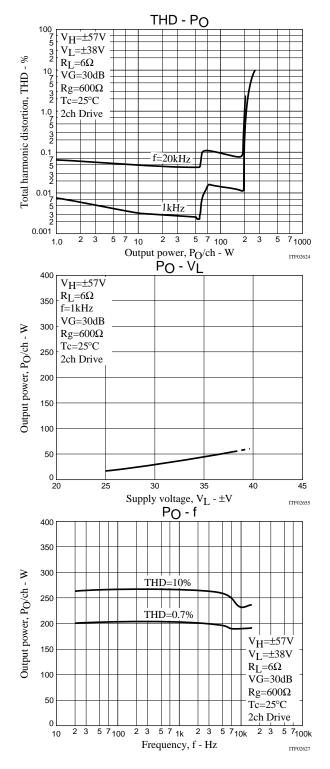
## Sample PCB Trace Pattern

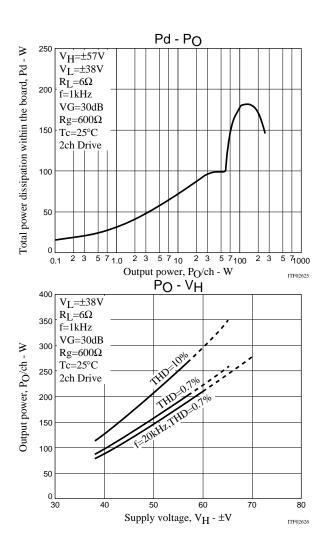


### Parts List

P.C.B. No.	STK412-150C-E/STK412-170C-E
R 01, 02	3.3kΩ 1W
R 03, 04	100Ω 1W
R 05, 06, 18, 19, (07, 20)	56kΩ 1/6W
R 08, 09, (10)	4.7Ω 1W
R 11, 12, (13)	4.7Ω 1/4W
R 14, 15, (16)	1.8kΩ 1/6W
R 17	33kΩ 1/4W
R 21, 22, (23)	1kΩ 1/6W
R 24, 25, 26, 27, (28, 29)	$0.1\Omega\pm10\%$ 5W
C 01, 02, 05, 06	100µF/100V
C 03, 04	100μF/63V
C 07, 08, (09)	ЗрF
C 10, 11, (12)	0.1µF/100V
C 13, 14, (15)	100µF/10V
C 16, 17, (18)	2.2µF/50V
C 19, 20, (21)	470pF
C 22, 23, (24)	220pF
L 01, 02, (03)	ЗμН
D 01, 02	GZA18Y (SANYO)
J 01, 02, 03, 07	10mm
J 04, 05	12mm
J 06, 10	17mm
J 08, 09, 11, 12	14mm
J 13	5mm
J 14	N.C
J 15	33mm
J 16	30mm
J 17	5mm

#### **Evaluation Board Characteristics**





**Discontinued** 

## STK412-150C-E

[Thermal Design Example for STK412-150C-E] The thermal resistance,  $\theta$ c-a, of the heat sink for total power dissipation, Pd, within the hybrid IC is determined as follows. Condition 1: The hybrid IC substrate temperature, Tc, must not exceed 125°C.  $Pd \times \theta c-a + Ta < 125^{\circ}C$ (1) Ta: Guaranteed ambient temperature for the end product Condition 2: The junction temperature, Tj, of each power transistor must not exceed 150°C.  $Pd \times \theta c \cdot a + Pd/N \times \theta j \cdot c + Ta < 150^{\circ}C$  (2) N: Number of power transistors θj-c: Thermal resistance per power transistor However, the power dissipation, Pd, for the power transistors shall be allocated equally among the number of power transistors. The following inequalities result from solving equations (1) and (2) for  $\theta$ c-a.  $\theta c-a < (125 - Ta)/Pd$  .....(1)  $\theta c-a < (150 - Ta)/Pd - \theta j-c/N$  .....(2) Values that satisfy these two inequalities at the same time represent the required heat sink thermal resistance.

When the following specifications have been stipulated, the required heat sink thermal resistance can be determined from formulas (1)' and (2)'.

• Supply voltage	V <sub>H</sub> , V <sub>I</sub>
Load resistance	RL
• Guaranteed ambient temperature	Та

#### [Example]

When the IC supply voltage,  $V_H=\pm 57V$ ,  $V_L=\pm 38V$  and  $R_L$  is  $6\Omega$ , the total power dissipation, Pd, within the hybrid IC, will be a maximum of 180W at 1kHz for a continuous sine wave signal according to the Pd-Po characteristics. For the music signals normally handled by audio amplifiers, a value of 1/8PO max is generally used for Pd as an estimate of the power dissipation based on the type of continuous signal. (Note that the factor used may differ depending on the safety standard used.)

This is:

Pd  $\approx 85W$  (when 1/8PO max. = 19W).

The number of power transistors in audio amplifier block of these hybrid ICs, N, is 4, and the thermal resistance per transistor,  $\theta$ j-c, is 2.1°C/W. Therefore, the required heat sink thermal resistance for a guranteed ambient temperature, Ta, of 50°C will be as follows.

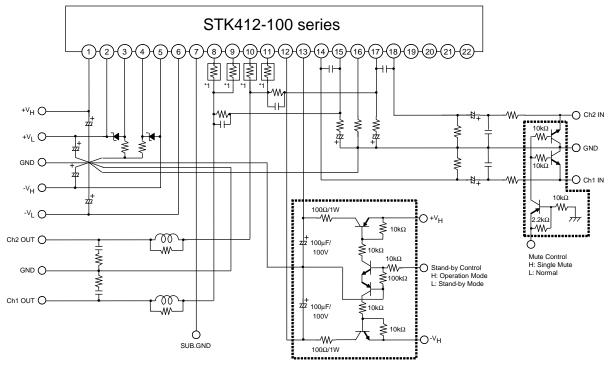
From formula (1)'	$\theta c$ -a < (125 – 50)/85
	< 0.88
From formula (2)'	$\theta$ c-a < (150 - 50)/85 - 1.4/4
	< 0.82

Therefore, the value of 0.82°C/W, which satisfies both of these formulae, is the required thermal resistance of the heat sink.

Note that this thermal design example assumes the use of a constant-voltage power supply, and is therefore not a verified design for any particular user's end product.

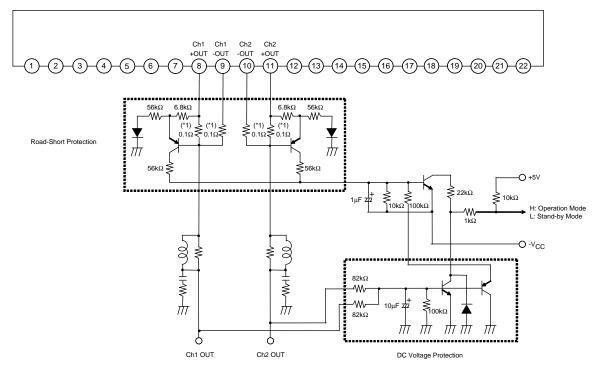
#### STK412-150C-E

#### STK412-100 Series Stand-by Control & Mute Control Application



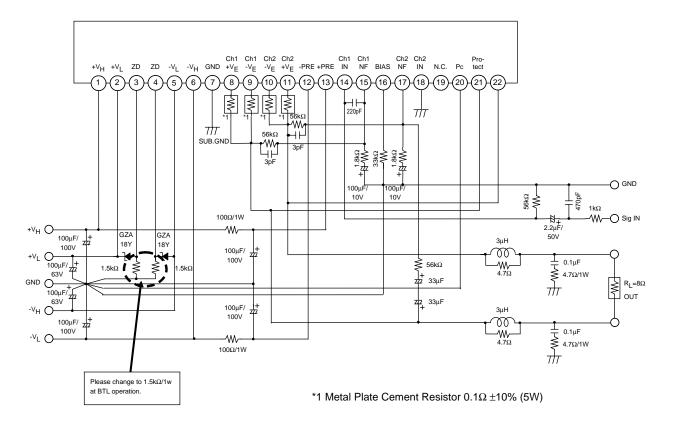
\*1 Metal Plate Cement Resistor 0.1 $\Omega \pm 10\%$  (5W)

#### STK412-100 Series Load-Short & DC Voltage Protect Application



\*1 Metal Plate Cement Resistor  $0.1\Omega \pm 10\%$  (5W)

#### STK412-150C-E/STK412-170C-E BTL Application



- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of March, 2009. Specifications and information herein are subject to change without notice.